

# 256K X 36 Dual I/O Dual Address Synchronous SRAM

#### **Features**

- Fast clock speed: 133, 100, and 83 MHz
- Fast Access Times: 4.0/5.0/6.0 ns Max.
- Single Clock Operation
- Single 3.3V -5% and +5% power supply VCC
- · Separate VCCQ for output buffer
- Two chip enables for simple depth expansion
- Address, Data Input, CE1X, CE2X, CE1Y, CE2Y, PTX, PTY, WEX, WEY, and Data Output Registers On-Chip
- · Concurrent Reads and Writes
- Two bidirectional Data Buses
- Can be configured as separate I/O
- · Pass-Through feature
- Asynchronous Output Enables (OEX, OEY)
- LVTTL-Compatible I/O
- · Self-Timed write
- Automatic power-down
- 176-Pin TQFP Package

### **Functional Description**

The CY7C1301A SRAM integrates 262,144 x 36 SRAM cells with advanced synchronous peripheral circuitry. It employs high-speed, low power CMOS designs using advanced triple-layer polysilicon, double-layer metal technology. Each memory cell consists of four transistors and two high valued resistors.

The CY7C1301A allows the user to concurrently perform reads, writes, or pass-through cycles in combination on the two data ports. The two address ports (AX, AY) determine the read or write locations for their respective data ports (DQX, DQY).

All input pins except output enable pins (OEX, OEY) are gated by registers controlled by a positive-edge-triggered clock input (CLK). The synchronous inputs include all addresses, all data inputs, depth-expansion chip enables (CE1X, CE2X, CE1Y and CE2Y), pass-through controls (PTX and PTY), and read-write control ( $\overline{WEX}$  and  $\overline{WEY}$ ).

The pass-through feature allows data to be passed from one port to the other, in either direction. The PTX# input must be asserted to pass data from port X to port Y. The PTY# will likewise pass data from port Y to port X. A pass-through operation takes precedence over a read operation.

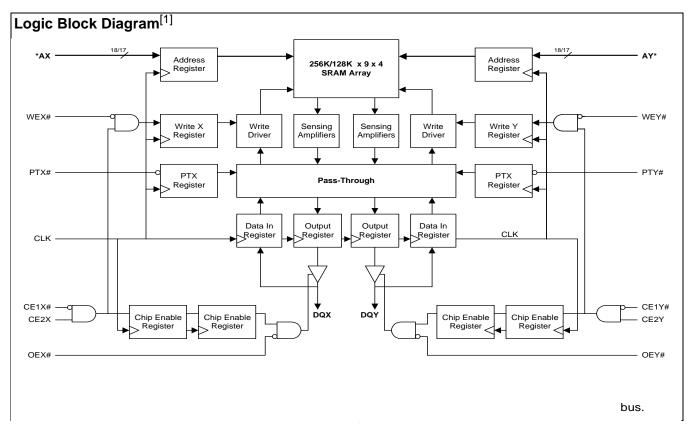
For the case when AX and AY are the same, certain protocols are followed. If both ports are read, the reads occur normally. If one port is written and the other is read, the read from the array will occur before the data is written. If both ports are written, only the data on DQY will be written to the array.

The CY7C1301A operate from a +3.3V power supply. All inputs and outputs are LVTTL compatible. These dual I/O, dual address synchronous SRAMs are well suited for ATM, Ethernet switches, routers, cell/frame buffers, SNA switches and shared memory applications.

The CY7C1301A device needs one extra cycle after power for proper power on reset. The extra cycle is needed after Vcc is stable on the device.

This device is available in a 176-pin TQFP package.





### **Selection Guide**

	-133	-100	-83
Maximum Access Time (ns)	4.0	5.0	6.0
Maximum Operating Current (mA)	400	350	300
Maximum CMOS Standby Current (mA)	100	100	100

Shaded areas contain advanced information.

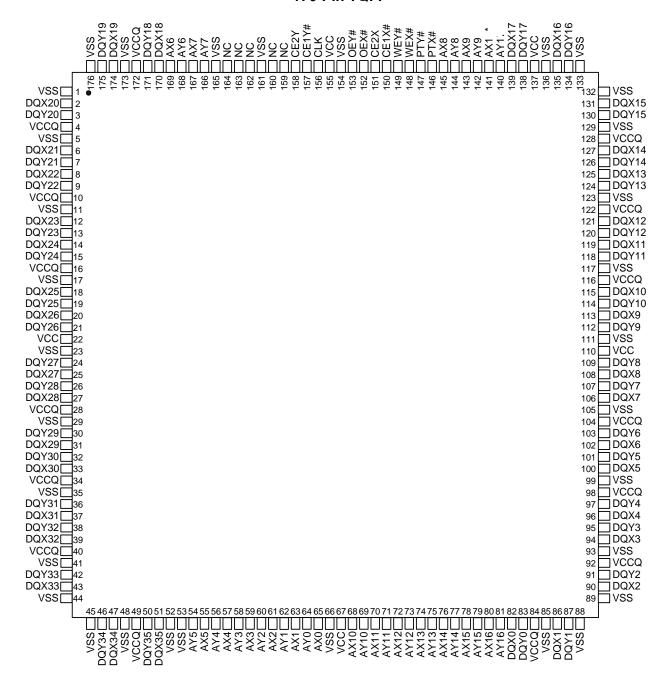
#### Note:

1. For 256 x 36 device, AX and AY are 18-bit wide busses.



### **Pin Configuration**

#### 176-Pin TQFP





## Pin Definitions(176-pin TQFP)

Name	I/O	Description
AX0-AX17	Input- Synchronous	Synchronous Address Inputs of Port X: Do not allow address pins to float.
AY0-AY17	Input- Synchronous	Synchronous Address Inputs of Port Y: Do not allow address pins to float.
WEX	Input- Synchronous	Read Write of Port X: WEX signal is a synchronous input that identifies whether the current loaded cycle is a Read or Write operation.
WEY	Input- Synchronous	Read Write of Port Y: WEY signal is a synchronous input that identifies whether the current loaded cycle is a Read or Write operation.
PTX	Input- Synchronous	Pass-Through of Port X: PTX signal is a synchronous input that enables passing Port X input to Port Y output.
PTY	Input- Synchronous	Pass-Through of Port Y: PTY signal is a synchronous input that enables passing Port Y input to Port X output.
ŌEX	Input	Asynchronous Output Enable of Port X: $\overline{OEX}$ must be LOW to read data. When $\overline{OEX}$ is HIGH, the DQXx pins are in high-impedance state.
ŌEY	Input	Asynchronous Output Enable of Port Y: $\overline{\text{OEY}}$ must be LOW to read data. When $\overline{\text{OEY}}$ is HIGH, the DQYx pins are in high-impedance state.
DQX0 - DQX35	Input/ Output	Data Inputs/Outputs of Port X: Both the data input path and data output path are registered and triggered by the rising edge of CLK.
DQY0 - DQY35	Input/ Output	Data Inputs/Outputs of Port Y: Both the data input path and data output path are registered and triggered by the rising edge of CLK.
CLK	Input- Synchronous	Clock: This is the clock input to this device. Except for $\overline{\text{OEX}}$ and $\overline{\text{OEY}}$ , all timing references of the address, data in, and all control signals for the device are made with respect to the rising edge of CLK.
CE1X	Input- Synchronous	Synchronous Active LOW Chip Enable Port X: CE1X is used with CE2X to enable Port X of this device. CE1X sampled HIGH at the rising edge of clock initiates a deselect cycle for Port X.
CE2X	input- Synchronous	Synchronous Active HIGH Chip Enable Port X: CE2X is used with CE1X to enable Port X of this device. CE2X sampled LOW at the rising edge of clock initiates a deselect cycle for Port X.
CE1Y	Input- Synchronous	Synchronous Active LOW Chip Enable Port Y: CE1Y is used with CE2Y to enable Port Y of this device. CE1Y sampled HIGH at the rising edge of clock initiates a deselect cycle for Port Y.
CE2Y	input- Synchronous	Synchronous Active HIGH Chip Enable Port Y: CE2Y is used with CE1Y to enable Port Y of this device. CE2Y sampled LOW at the rising edge of clock initiates a deselect cycle for Port Y.
V <sub>CC</sub>	Supply	Power Supply: +3.3V –5% and +5%.
$V_{SS}$	Ground	Ground: GND.
V <sub>SS</sub>	Ground	Ground: GND. No chip current flows through these pins. However, user needs to connect GND to these pins. Pins 140 and 141 are $V_{SS}$ for 128K x 36 device.
V <sub>CCQ</sub>	I/O Supply	Output Buffer Supply: +3.3V –5% and +5%.
NC	-	No Connect: These signals are not internally connected. User can connect them to $V_{CC}$ , $V_{SS}$ , or any signal lines or simply leave them floating.



## Cycle Description Truth Table<sup>[2, 3, 4, 5, 6, 7, 8, 9]</sup>

Operation	CE1X	CE2X	CE1Y	CE2Y	WEX	WEY	PTX	PTY
DESELECT CYCLE	Н	Х	Н	X	Х	Χ	Х	Х
DESELECT CYCLE	Х	L	Х	L	Х	Х	Х	Х
WRITE PORT X	L	Н	Х	Х	0	Х	Х	Х
WRITE PORT Y	Х	Х	L	Н	Х	0	Х	Х
PASS-THROUGH from X to Y	L	Н	L	Н	Х	Х	0	Х
PASS-THROUGH from Y to X	L	Н	L	Н	Х	Х	Х	0
READ PORT X	L	Н	Х	Х	1	Х	1	1
READ PORT Y	Х	Х	L	Н	Х	1	1	1

### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.) Storage Temperature ......-55°C to +125°C Ambient Temperature with Power Applied......-10°C to +85°C Supply Voltage on V<sub>DD</sub> Relative to GND......-0.5V to +4.6V 

DC Input Voltage <sup>[10]</sup>	–0.5V to $V_{CCQ}$ + 0.5V
Current into Outputs (LOW)	20 mA
Static Discharge Voltage(per MIL-STD-883, Method 3015)	>2001V
Latch-Up Current	>200 mA.

### **Operating Range**

Range	Ambient Temperature <sup>[11]</sup>	V <sub>DD</sub> /V <sub>DDQ</sub>
Com'l	0°C to +70°C	3.3V ± 5%

#### Notes:

- X means "Don't Care." H means logic HIGH. L means logic LOW.

  All inputs except OEX and OEY must meet setup and hold times around the rising edge (LOW to HIGH) of CLK.

  OEX and OEY must be asserted to avoid bus contention during Write and Pass-Through cycles. For a Write and Pass-Through operation following a READ operation, OEX/OEY must be HIGH before the input data required setup time plus High-Z time for OEX/OEY and staying HIGH throughout the input data hold time. Operation number 3 6 can be used in any combination.

  Operation number 4 and 7, 3 and 8, 7 and 8 can be combined.
- Operation number 5 can not be combined with operation number 7 or 8 because Pass-Through operation has higher priority over a READ operation.
   Operation number 6 can not be combined with operation number 7 or 8 because Pass-Through operation has higher priority over a READ operation.
   This device contains circuitry that will ensure the outputs will be in High-Z during power-up
   Minimum voltage equals -2.0V for pulse duration less than 20 ns.
   T<sub>A</sub> is the case temperature.



## **Electrical Characteristics** Over the Operating Range

Parameter	Description	Test Conditi	ons	Min.	Max.	Unit
V <sub>DD</sub>	Power Supply Voltage			3.135	3.465	V
V <sub>DDQ</sub>	I/O Supply Voltage			3.135	3.465	V
V <sub>OH</sub>	Output HIGH Voltage	$V_{DD} = Min., I_{OH} = -4.0 \text{ mA}$		2.4		V
V <sub>OL</sub>	Output LOW Voltage	$V_{DD} = Min., I_{OL} = 8.0 \text{ mA}$			0.4	V
V <sub>IH</sub>	Input HIGH Voltage <sup>[12]</sup>			2.0	V <sub>CC</sub> + 0.5V	V
V <sub>IL</sub>	Input LOW Voltage <sup>[13]</sup>			-0.5	0.8	V
I <sub>X</sub>	Input Load Current	$GND \le V_{IN} \le V_{DDQ}$			5	μΑ
l <sub>OZ</sub>	Output Leakage Current	$GND \le V_{IN} \le V_{DDQ}$ , Output Disabled		-5	5	μΑ
I <sub>CC</sub>	V <sub>DD</sub> Operating	$V_{DD} = Max., I_{OUT} = 0 mA,$	7.0-ns cycle, 133 MHz		400	mA
	Supply	$f = f_{MAX} = 1/t_{CYC}$	7.5-ns cycle, 100 MHz		350	mA
			10.0-ns cycle, 83MHz		300	mA
I <sub>SB</sub>	Automatic CE Power-Down Current—CMOS Inputs	$\begin{aligned} &\text{Max. V}_{\text{DD}}, \text{Device Deselected}^{[14]}, \\ &\text{V}_{\text{IN}} \leq 0.3 \text{V or V}_{\text{IN}} \geq \text{V}_{\text{DDQ}} - 0.3 \text{V}, \\ &\text{f} = 0 \end{aligned}$	All speed grades		100	mA

#### Note:

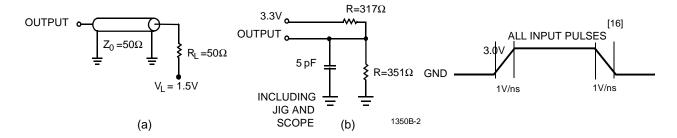
- Overshoot: V<sub>IH</sub> ≤ +6.0V for t ≤ t<sub>KC /2</sub>
   Undershoot: V<sub>IL</sub> ≤ -2.0V for t ≤ t<sub>KC /2</sub>.
   "Device Deselected" means the device is in Power -Down mode as defined in the truth table.



## Capacitance<sup>[15]</sup>

Parameter	Description	Test Conditions	Max.	Unit
C <sub>IN</sub>	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz},$	6	pF
C <sub>CLK</sub>	Clock Input Capacitance	$V_{CC} = 3.3V,$ $V_{CCQ} = 3.3V$	6	pF
C <sub>I/O</sub>	Input/Output Capacitance		8	pF

## **AC Test Loads and Waveforms**<sup>[16]</sup>



### **Thermal Resistance**

Description	scription Test Conditions		TQFP Typ.	Units	Notes
Thermal Resistance (Junction to Ambient)	(@200lfm) Single-layer printed circuit board	$\Theta_{JA}$	40	°C/W	15
Thermal Resistance (Junction to Ambient)	(@200lfm) Four-layer printed circuit board	$\Theta_{\sf JC}$	35	°C/W	15
Thermal Resistance (Junction to Board)	Bottom	$\Theta_{JA}$	23	°C/W	15
Thermal Resistance (Junction to Case)	Тор	$\Theta_{\sf JC}$	9	°C/W	15

#### Notes:

<sup>15.</sup> Tested initially and after any design or process change that may affect these parameters.
16. AC test conditions assume signal transition time of 1 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading shown in part (a) of AC Test Loads.



## Switching Characteristics Over the Operating Range<sup>[16, 17, 18]</sup>

Parameter Description		33	-1	00		-80	
		Max.	Min.	Max.	Min.	Max.	Unit
	•	•		•		•	•
Clock cycle time	7.5		10		12		ns
Clock HIGH time	3.0		3.5		4.0		ns
Clock LOW time	3.0		3.5		4.0		ns
			_				
Clock to output valid		4.0		5.0		6.0	ns
Clock to output invalid	1.5		1.5		1.5		ns
Clock to output in Low-Z <sup>[19]</sup>	0		0		0		ns
Clock to output in High-Z <sup>[19]</sup>		3.0		3.0		3.0	ns
OEX#/OEY# to output valid		4.0		5.0		6.0	ns
OEX#/OEY# to output in Low-Z <sup>[19]</sup>	0		0		0		ns
OEX#/OEY# to output in High-Z <sup>[19]</sup>		3.0		3.0		3.0	ns
			_				
Addresses, Controls and Data In	1.5		1.5		2.0		ns
Addresses, Controls and Data In	0.5		0.5		0.5		ns
	Clock cycle time Clock HIGH time Clock LOW time  Clock to output valid Clock to output invalid Clock to output in Low-Z <sup>[19]</sup> Clock to output in High-Z <sup>[19]</sup> OEX#/OEY# to output valid OEX#/OEY# to output in Low-Z <sup>[19]</sup> OEX#/OEY# to output in High-Z <sup>[19]</sup> Addresses, Controls and Data In	Clock cycle time 7.5  Clock HIGH time 3.0  Clock LOW time 3.0  Clock to output valid  Clock to output invalid 1.5  Clock to output in Low-Z <sup>[19]</sup> 0  Clock to output in High-Z <sup>[19]</sup> 0  CEX#/OEY# to output valid 0  OEX#/OEY# to output in Low-Z <sup>[19]</sup> 0  Addresses, Controls and Data In 1.5	Clock cycle time         7.5           Clock HIGH time         3.0           Clock LOW time         3.0           Clock to output valid         4.0           Clock to output invalid         1.5           Clock to output in Low-Z <sup>[19]</sup> 0           Clock to output in High-Z <sup>[19]</sup> 3.0           OEX#/OEY# to output valid         4.0           OEX#/OEY# to output in Low-Z <sup>[19]</sup> 0           OEX#/OEY# to output in High-Z <sup>[19]</sup> 3.0           Addresses, Controls and Data In         1.5	Description         Min.         Max.         Min.           Clock cycle time         7.5         10           Clock HIGH time         3.0         3.5           Clock LOW time         3.0         3.5           Clock to output valid         1.5         1.5           Clock to output in Low-Z <sup>[19]</sup> 0         0           Clock to output in High-Z <sup>[19]</sup> 3.0         0           Clock to output in High-Z <sup>[19]</sup> 3.0         0           OEX#/OEY# to output valid         4.0         0           OEX#/OEY# to output in Low-Z <sup>[19]</sup> 0         0           OEX#/OEY# to output in High-Z <sup>[19]</sup> 3.0         1.5           Addresses, Controls and Data In         1.5         1.5	Description         Min.         Max.         Min.         Max.           Clock cycle time         7.5         10           Clock HIGH time         3.0         3.5           Clock LOW time         3.0         3.5           Clock to output valid         4.0         5.0           Clock to output invalid         1.5         1.5           Clock to output in Low-Z <sup>[19]</sup> 0         0           Clock to output in High-Z <sup>[19]</sup> 3.0         3.0           OEX#/OEY# to output valid         4.0         5.0           OEX#/OEY# to output in Low-Z <sup>[19]</sup> 0         0           OEX#/OEY# to output in High-Z <sup>[19]</sup> 3.0         3.0           Addresses, Controls and Data In         1.5         1.5	Description         Min.         Max.         Min.         Max.         Min.           Clock cycle time         7.5         10         12           Clock HIGH time         3.0         3.5         4.0           Clock LOW time         3.0         3.5         4.0           Clock to output valid         1.5         1.5         1.5           Clock to output in Low-Z <sup>[19]</sup> 0         0         0           Clock to output in High-Z <sup>[19]</sup> 3.0         3.0         3.0           OEX#/OEY# to output valid         4.0         5.0         0           OEX#/OEY# to output in Low-Z <sup>[19]</sup> 0         0         0           OEX#/OEY# to output in High-Z <sup>[19]</sup> 3.0         3.0           Addresses, Controls and Data In         1.5         1.5         2.0	Description   Min.   Max.   Min.   Max.   Min.   Max.   Min.   Max.

Shaded areas contain advance information.

#### Notes:

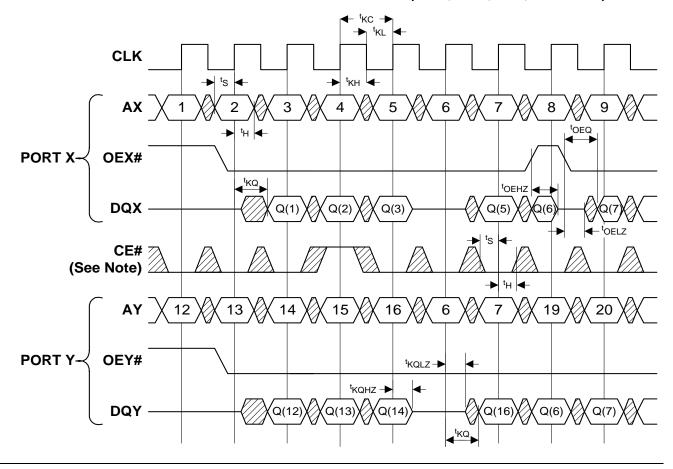
<sup>17.</sup>  $t_{CHZ}, t_{CLZ}, t_{OEV}, t_{EOLZ}$ , and  $t_{EOHZ}$  are specified with A/C test conditions shown in part (a) of AC Test Loads. Transition is measured  $\pm$  200 mV from steady-state

 <sup>18.</sup> At any given voltage and temperature, t<sub>EOHZ</sub> is less than t<sub>EOLZ</sub> and t<sub>CHZ</sub> is less than t<sub>CLZ</sub> to eliminate bus contention between SRAMs when sharing the same data bus. These specifications do not imply a bus contention condition, but reflect parameters guaranteed over worst case user conditions. Device is designed to achieve High-Z prior to Low-Z under the same system conditions.
 19. This parameter is sampled and not 100% tested.
 20. CE LOW means (CE1X and CE1Y) equals LOW and (CE2X and CE2Y) equals HIGH. CE HIGH means (CE1X and CE1Y) equals HIGH or (CE2X and CE2Y) equals LOW.



## Switching Waveforms [20]

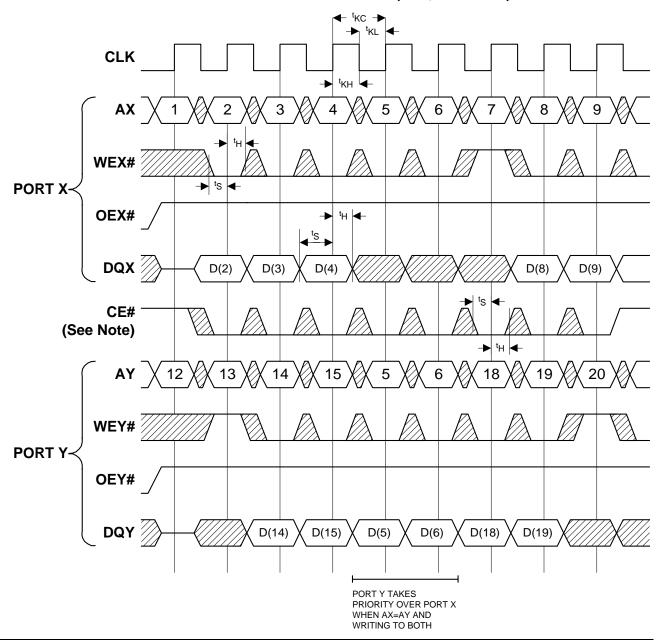
## READ CYCLE TIMING FROM BOTH PORTS (WEX, WEY, PTX, PTY HIGH)[19]





## Switching Waveforms (continued)[20]

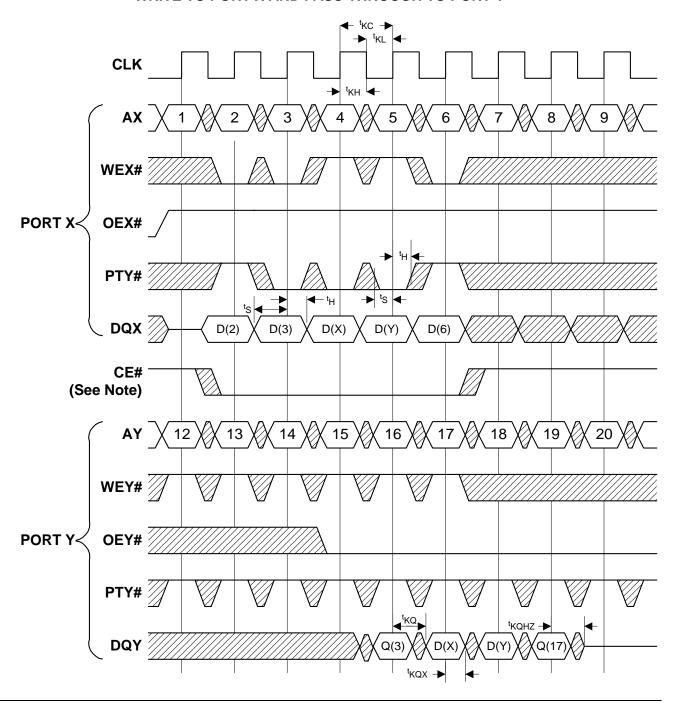
## WRITE CYCLE TIMING TO BOTH PORTS (PTX, PTY HIGH)[19]





## Switching Waveforms (continued)<sup>[20]</sup>

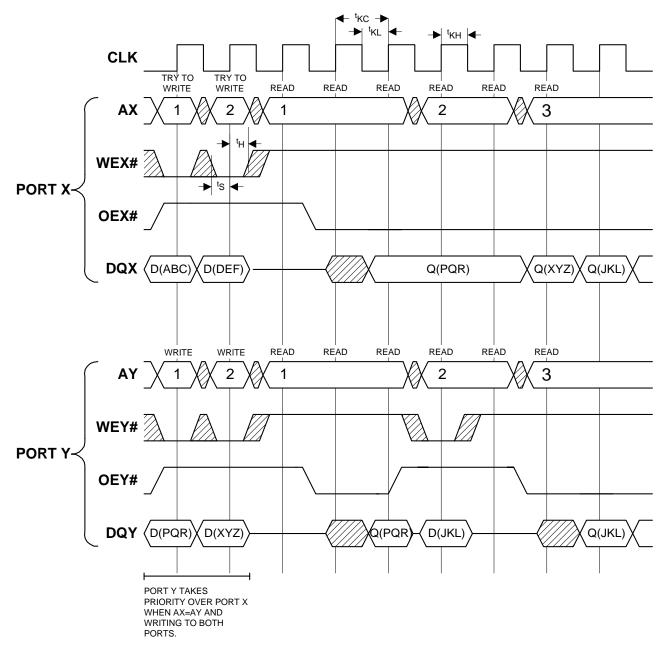
## WRITE TO PORT X AND PASS-THROUGH TO PORT Y[19]





## Switching Waveforms (continued)[20]

### COMBINATION READ/WRITE WITH SAME ADDRESS ON EACH PORT



PTX# = PTY# = HIGH

D(Value) = Value is the input of the data port. Q(Value) = Value is the output of the data port.



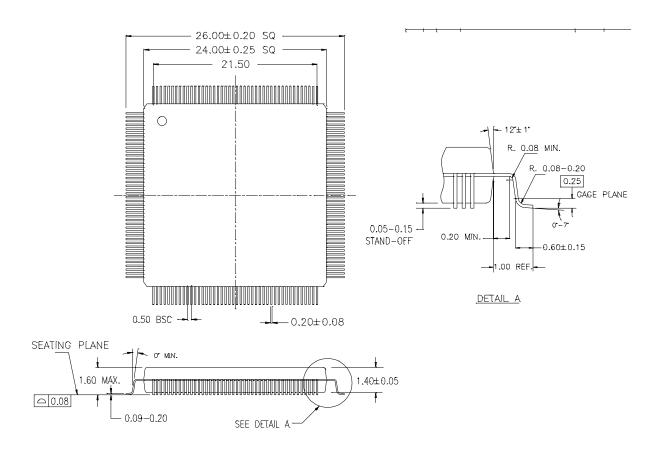
## **Ordering Information**

Speed (MHz)	Ordering Code	Package Name	Package Type	Operating Range		
133	CY7C1301A-133AC	ACx	176 Pin TQFP	Commercial		
100	CY7C1301A-100AC					
83	CY7C1301A-83BGC					
Shaded areas	Shaded areas contain advance information.					



## **Package Diagram**

### 176-Lead Thin Quad Flat Pack (24x24x1.4 mm) A176





CY7C1301A

Document Title: CY7C1301A - 256K x 36 Dual I/O Dual Address Synchronous SRAM Document: 38-05076				
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	107305	06/08/01	NSL	New Data Sheet